74HC02; 74HCT02

Quad 2-input NOR gate Rev. 5 — 26 November 2015

Product data sheet

1. **General description**

The 74HC02; 74HCT02 is a quad 2-input NOR gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features and benefits 2.

Input levels:

◆ For 74HC02: CMOS level ◆ For 74HCT02: TTL level

- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

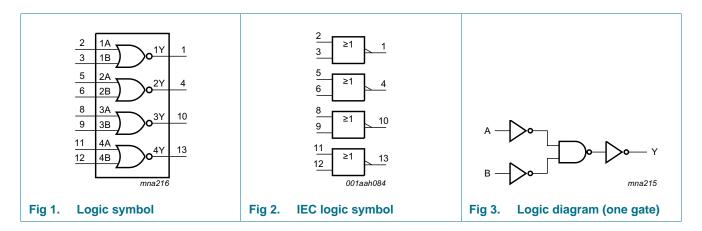
Ordering information 3.

Table 1. **Ordering information**

Type number	Package								
	Temperature range	Name	Description	Version					
74HC02D	−40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1					
74HCT02D			3.9 mm						
74HC02DB	−40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body	SOT337-1					
74HCT02DB			width 5.3 mm						
74HC02PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1					
74HCT02PW			body width 4.4 mm						
74HC02BQ	−40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very	SOT762-1					
74HCT02BQ			thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm						

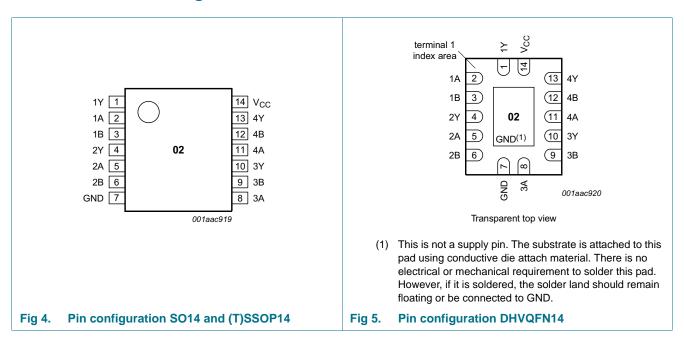


4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Y to 4Y	1, 4, 10, 13	data output
1A to 4A	2, 5, 8, 11	data input
1B to 4B	3, 6, 9,12	data input
GND	7	ground (0 V)
V _{CC}	14	supply voltage

74HC_HCT02

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6. Functional description

Table 3. Function table[1]

Input	Output	
nA	nB	nY
L	L	Н
X	Н	L
Н	X	L

^[1] H = HIGH voltage level;

L = LOW voltage level;

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	50	mA
I_{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO14, (T)SSOP14 and DHVQFN14 packages	[2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For (T)SSOP14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

For DHVQFN14 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC02			74HCT02	2	Unit	
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

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X = don't care.

^[2] For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC02										
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH} HIGH-level		$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	20	-	40	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT0	2									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
(I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
		I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 5.2 mA	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	20	-	40	μА
Δl _{CC}	additional supply current	per input pin; $V_{I} = V_{CC} - 2.1 \text{ V; } I_{O} = 0 \text{ A;}$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	150	540	-	675	-	735	μА
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $C_L = 50 pF$; for test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions		25 °C		-40 °C to	Unit	
				Тур	Max	Max (85 °C)	Max (125 °C)	
74HC02								
t _{pd}	propagation delay	nA, nB to nY; see Figure 6	1					
	V _{CC} = 2.0 V	-	25	90	115	135	ns	
		V _{CC} = 4.5 V	-	9	18	23	27	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	7	-	-	-	ns
		V _{CC} = 6.0 V	-	7	15	20	23	ns
t _t	transition time	see Figure 6	1					
		V _{CC} = 2.0 V	-	19	75	95	110	ns
		V _{CC} = 4.5 V	-	7	15	19	22	ns
		V _{CC} = 6.0 V	-	6	13	16	19	ns
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC}	-	22	-	-	-	pF

Table 7. Dynamic characteristics

 $GND = 0 \ V; \ C_L = 50 \ pF;$ for test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+125 °C	Unit
			Min	Тур	Max	Max (85 °C)	Max (125 °C)	
74HCT02	2							
t _{pd} propag	propagation delay	nA, nB to nY; see Figure 6						
		V _{CC} = 4.5 V	-	11	19	24	29	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	9	-	-	-	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u> [2]	-	7	15	19	22	ns
C _{PD}	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC} - 1.5 \text{ V}$	-	24	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

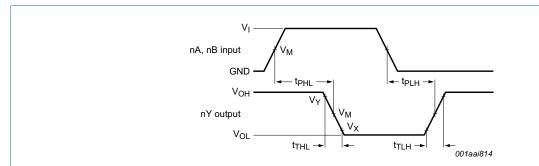
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

11. Waveforms



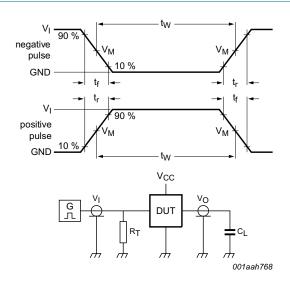
Measurement points are given in Table 9.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. Input to output propagation delays

Table 8. Measurement points

Туре	Input	Output						Output	
	V_{M}	V_{M}	V _X	V _Y					
74HC02	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}					
74HCT02	1.3 V	1.3 V	0.1V _{CC}	0.9V _{CC}					



Test data is given in Table 9.

Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

Fig 7. Test circuit for measuring switching times

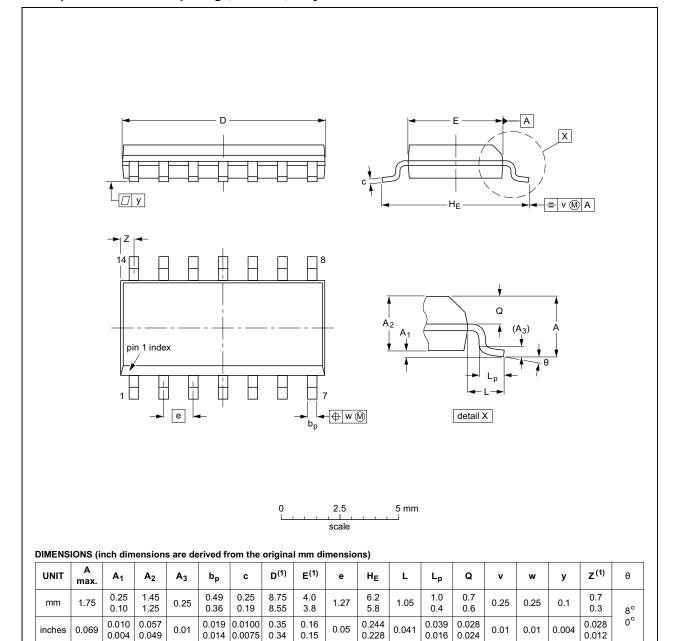
Table 9. Test data

Туре	Input L		Load	Test
	VI	t _r , t _f	CL	
74HC02	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT02	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
	IEC	JEDEC	JEITA		PROJECTION	1990E DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

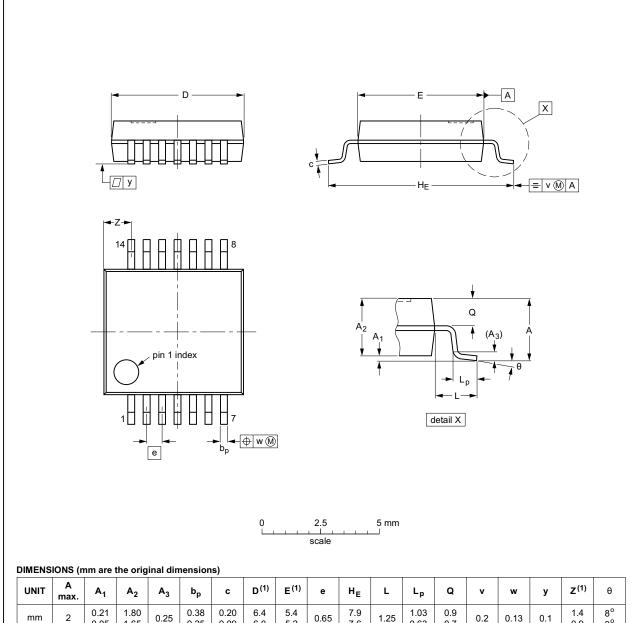
Fig 8. Package outline SOT108-1 (SO14)

74HC_HCT02

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

		EUROPEAN	ISSUE DATE				
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE		
	MO-150				99-12-27 03-02-19		
_	IEC				IEC JEDEC JEHA		

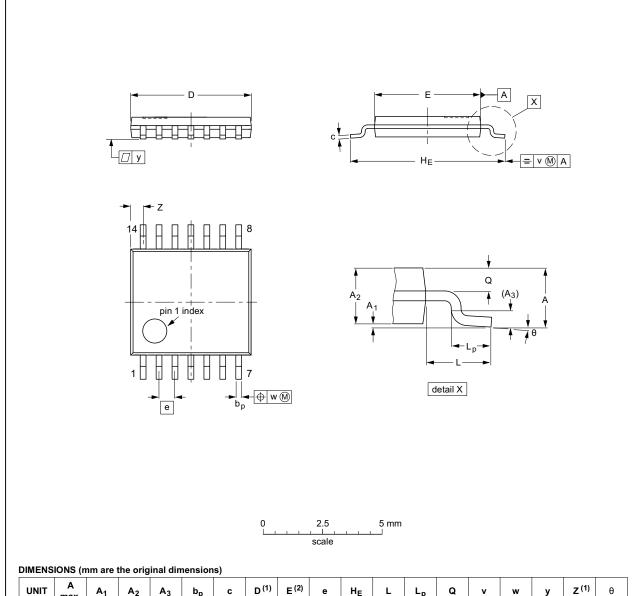
Package outline SOT337-1 (SSOP14)

74HC_HCT02

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



UNI	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

(OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VE	/ERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
S	SOT402-1		MO-153			99-12-27 03-02-18
8	SOT402-1		MO-153			∌

Fig 10. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm

SOT762-1

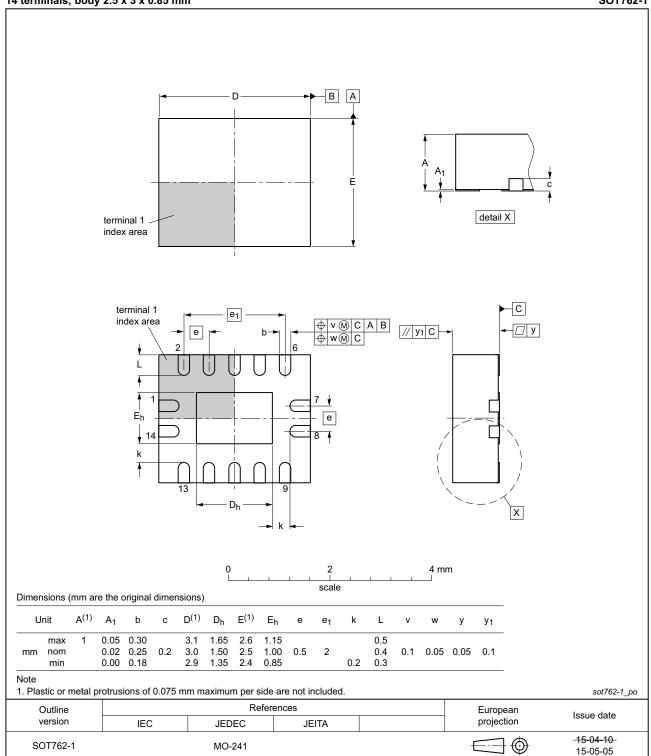


Fig 11. Package outline SOT762-1 (DHVQFN14)

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes					
74HC_HCT02 v.5	20151126	Product data sheet	-	74HC_HCT02 v.4					
Modifications:	 Type numbers 74HC 	Type numbers 74HC02N and 74HCT02N (SOT27-1) removed.							
74HC_HCT02 v.4	20120904	Product data sheet	-	74HC_HCT02 v.3					
Modifications:	 Conditions for V_{OH}, 	 Conditions for V_{OH}, I_I and I_{CC} updated to the family specification (errata). 							
74HC_HCT02 v.3	20080918	Product data sheet	-	74HC_HCT02_CNV v.2					
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 								
	 Legal texts have been adapted to the new company name where appropriate. 								
	 Added type numbers 74HC02BQ and 74HCT02BQ (DHVQFN14 package) 								
74HC_HCT02_CNV v.2	19970827	Product specification	-	-					

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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